

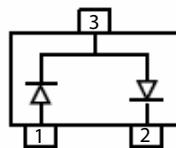
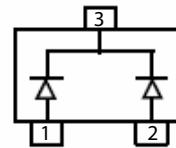
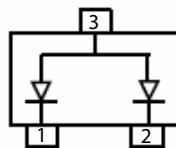
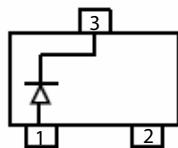
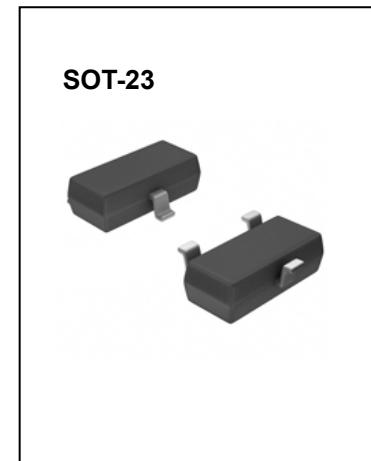
## SOT-23 Plastic-Encapsulate Diodes

**MMBD4148A/SE/CC/CA** SWITCHING DIODES

### FEATURES

#### Power Dissipation

PD : 350 mW (Tamb=25°C)



### MARKING:

MMBD4148A:5H

MMBD4148CA :D6

MMBD4148CC :D5

MBD4148SE :D4

### Maximum Ratings @T<sub>A</sub>=25

Parameter	Symbol	Limits			Unit
Peak Repetitive Peak reverse voltage	V <sub>RRM</sub>				
Working Peak Reverse Voltage	V <sub>RWM</sub>	100			V
DC Blocking Voltage	V <sub>R</sub>				
Forward Continuous Current	I <sub>FM</sub>	200			mA
Power Dissipation	Pd	350			mW
Storage temperature	T <sub>STG</sub>	-55-150			°C

### Electrical Characteristics@T<sub>A</sub>=25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse Breakdown Voltage	V <sub>(BR)R1</sub>	100			V	IR=100μA
	V <sub>(BR)R2</sub>	75			V	IR=5μA
Forward voltage	V <sub>F</sub>			1	V	I <sub>F</sub> =10mA
Reverse current	I <sub>R1</sub>			25	nA	V <sub>R</sub> =25V
	I <sub>R2</sub>			5	uA	V <sub>R</sub> =75V
Diode Capacitance	C <sub>D</sub>			4	pF	V <sub>R</sub> =0V,f=1MHz
Reverse Recovery Time	t <sub>rr</sub>			4	nS	I <sub>F</sub> =10mA,V <sub>R</sub> =6V I <sub>rr</sub> =0.1XI <sub>R</sub> ,R <sub>L</sub> =100Ω

## Typical Characteristics

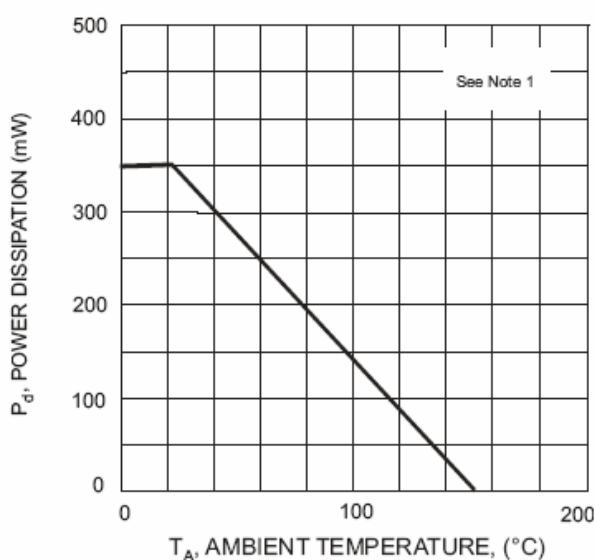


Fig. 1 Power Derating Curve

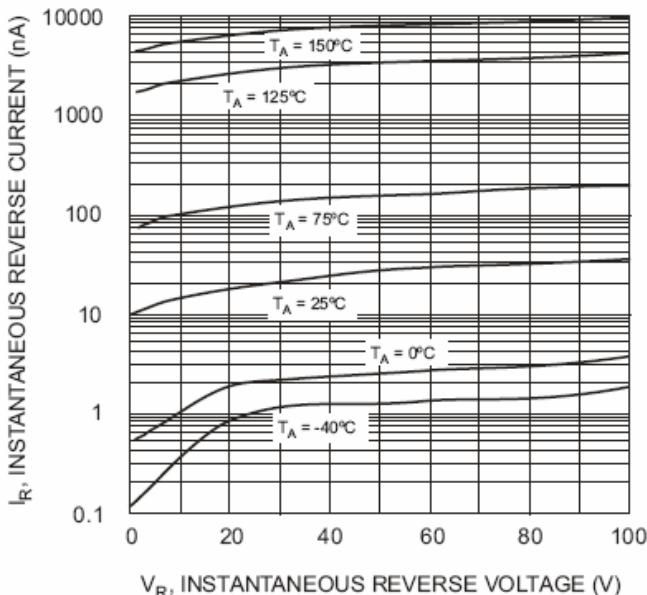


Fig. 3 Typical Reverse Characteristics

## MMBD4148A/SE/CC/CA

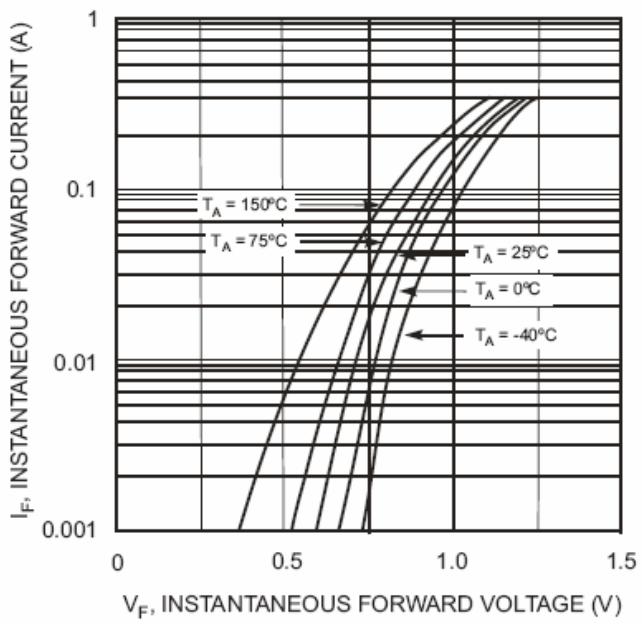


Fig. 2 Forward Characteristics

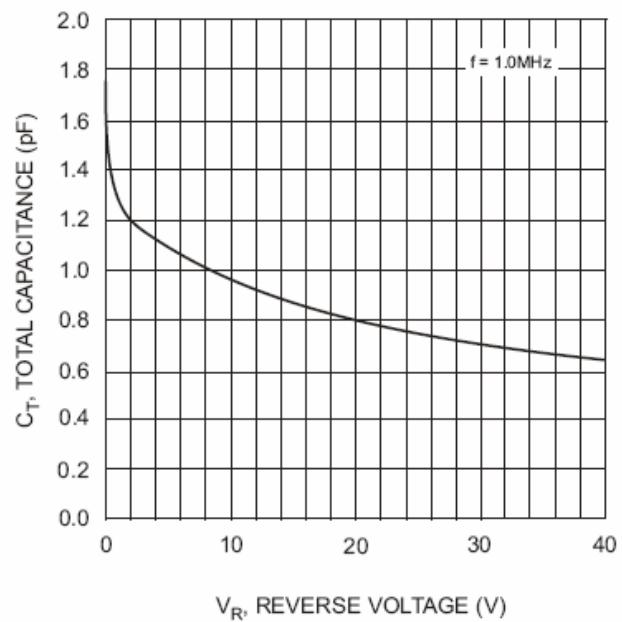


Fig. 4 Typical Capacitance vs. Reverse Voltage